#### 04000EC402052002

Reg No.:

#### Name:

the second commiss 15 months

APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

Eighth Semester B.Tech Degree Examination June 2022 (2015 Scheme)

## **Course Code: EC402**

## **Course Name: NANOELECTRONICS**

Max. Marks: 100

#### **Duration: 3 Hours**

Marke

Pages: 2

## PART A

|   |           | Answer any two juit questions, each carries 15 marks.                            | IVIAI KS |
|---|-----------|--|----------|
| 1 | a)        | Show that density of states in a 2D nanostructure is independent of energy.      | (10)     |
|   | <b>b)</b> | Explain quantum mechanical coherence.  | (5)      |
| 2 | a)        | Illustrate the process of molecular beam epitaxy for fabricating nano layers.    | (10)     |
|   | b)        | List any five properties of graphene   | (5)      |
| 3 | a)        | Differentiate between dry and wet oxidation methods for fabricating nano layers. | (5)      |
|   | b)        | Explain Sol-Gel process for fabricating nano particles                           | (10)     |
|   |           |  |          |

#### PART B

## Answer any two full questions, each carries 15 marks.

- 4 a) Write notes on Si Ge heterostructures and why it is used for fabricating high (10)frequency transistors.
  - (5) b) With the aid of diagrams, explain the concept of multiple quantum well and its types.
- (10)Explain the different interactions taking place between specimen and electron 5 a) beam in a SEM.
  - (5) Explain the concept of zone folding in superlattice. b)
- Illustrate the working principle and modes of operation of Scanning Tunneling (10)6 a) Microscope.
  - (5) b) Explain how band gap can be calculated using UV visible absorption spectroscopy?

### PART C

## Answer any two full questions, each carries 20 marks.

7 a) Explain Coulomb blockade effect. Draw the schematic and equivalent circuit (10)diagrams and explain the working of single electron transisitor.

# 04000EC402052002

| (ter | <b>b</b> ) | Illustrate the working of quantum dot LED.   | (5)  |
|------|------------|--|------|
|      | c)         | With the help of neat schematic diagram, explain MODFETs.                            | (5)  |
| 8    | a)         | Explain the process of quantum transport in nanostructures, Derive Landauer          | (10) |
|      |            | formula and explain its significance.  |      |
|      | b)         | Explain the effect of magnetic field in the energy levels and density of states in a | (5)  |
|      |            | 2D system.   |      |
|      | c)         | Explain (a) velocity overshoot effect (b) real space transfer                        | (5)  |
| 9    | a)         | Explain CNT transistors and its types.   | (10) |
|      | b)         | Explain Aharanov – Bohm effect   | (5)  |
|      | c)         | Explain perpendicular transport in quantum structures.                               | (5)  |
|      |            |  |      |

à.